

MSM271024

65,536-Word x 16-Bit UV EPROM

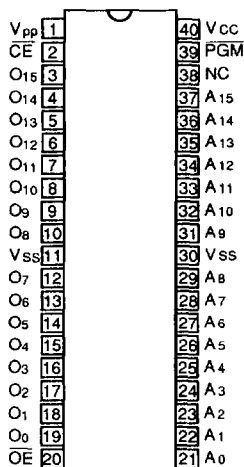
GENERAL DESCRIPTION

The MSM271024 is a 65,536-word x 16-bit ultraviolet erasable and electrically programmable read-only memory. The MSM271024 is manufactured by the N channel double silicon gate MOS technology and is contained in the 40-pin package.

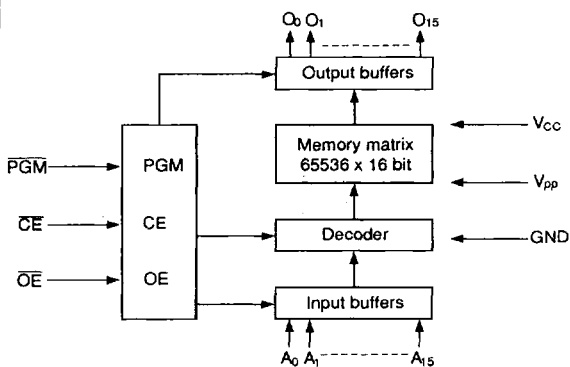
FEATURES

- +5V single power supply
- 65,536-word x 16-bit configuration
- Access time:
 - MAX 150 ns (MSM271024-15)
 - MAX 200 ns (MSM271024-20)
- Power consumption
 - MAX630 mW (during operation)
 - MAX184 mW (during standby)
- Completely static operation
- INPUT/OUTPUT TTL compatible (three state output)

PIN CONFIGURATION (TOP VIEW)



FUNCTIONAL BLOCK DIAGRAM



This specification may be changed without notification.

TRUTH TABLE

Mode \ Pins	CE (2)	OE (20)	PGM (39)	V _{pp} (1)	V _{CC} (40)	Outputs
Read	V _{IL}	V _{IL}	—	—	+5V	D _{OUT}
Output Disable	V _{IL}	V _{IH}	—	—	+5V	High impedance
Standby	V _{IH}	—	—	—	+5V	High impedance
Program	V _{IL}	V _{IH}	V _{IL}	+12.75V	+6.25V	D _{IN}
Program Verify	V _{IL}	V _{IL}	V _{IH}	+12.75V	+6.25V	D _{OUT}
Program Inhibit	V _{IH}	—	—	+12.75V	+6.25V	High impedance

—: Can be either V_{IL} or V_{IH}

ELECTRICAL CHARACTERISTICS ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Conditions	Value	Unit
Temperature Under Bias	T _a	————	0 ~ 70	°C
Storage Temperature	T _{stg}	————	-55 ~ 125	°C
Input Voltage	V _{IN}	————	-0.6 ~ 13.5	V
Output Voltage	V _{OUT}	————	-0.6 ~ 7	V
Supply Voltage	V _{CC}	————	-0.6 ~ 7	V
Program Voltage	V _{pp}	————	-0.6 ~ 14	V

The voltage referenced to GND.

Note: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

READ OPERATION RECOMMENDED OPERATING CONDITIONS

(T_a = 0 ~ 70°C)

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Supply Voltage	V _{CC}	V _{CC} = 5V ± 5%	4.75	5.0	5.25	V
V _{pp} Voltage	V _{pp}		-0.1	—	V _{CC} + 1	V
"H" Level Input Voltage	V _{IH}		2.0	—	6.25	V
"L" Level Input Voltage	V _{IL}		-0.1	—	0.8	V

The voltage referenced to GND.

DC CHARACTERISTICS

($V_{CC} = 5V \pm 5\%$, $T_a = 0 \sim 70^\circ C$)

Parameter	Symbol	Conditions	MSM271024			Unit	Notes
			Min.	Typ.	Max.		
Input Leakage Current	I_{LI}	$V_{IN} = 5.25V$	—	—	10	μA	
Output Leakage Current	I_{LO}	$V_{OUT} = 5.25V$	—	—	10	μA	
V_{CC} Power Current (Standby)	I_{CC1}	$\overline{CE} = V_{IH}$	—	—	35	mA	
V_{CC} Power Current (Operation)	I_{CC2}	$\overline{CE} = V_{IL}$	—	—	120	mA	
Program Power Current	I_{pp}	$V_{pp} = V_{CC}$	—	—	10	μA	
Input Voltage "H" Level	V_{IH}	—	2.0	—	$V_{CC} + 1$	V	
Input Voltage "L" Level	V_{IL}	—	-0.1	—	0.8	V	
Output Voltage "H" Level	V_{OH}	$I_{OH} = -400 \mu A$	2.4	—	—	V	
Output Voltage "L" Level	V_{OL}	$I_{OL} = 2.1 \text{ mA}$	—	—	0.45	V	

AC CHARACTERISTICS

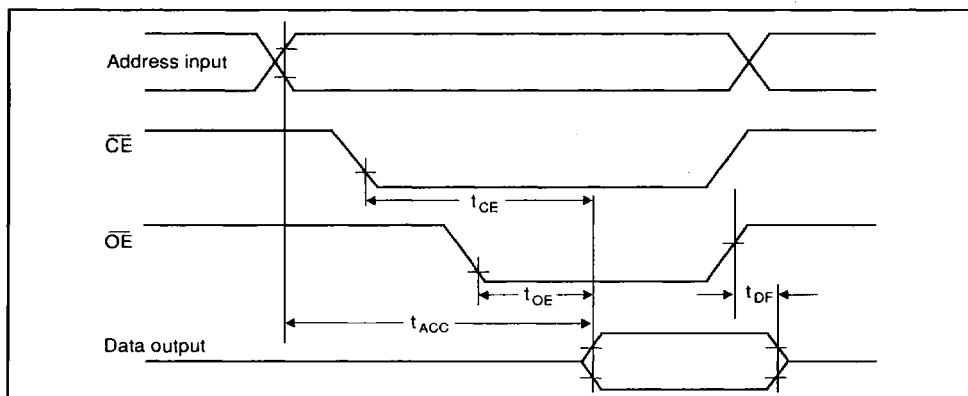
($V_{CC} = 5V \pm 5\%$, $T_a = 0 \sim 70^\circ C$)

Parameter	Symbol	Conditions	271024-15		271024-20		Unit	Notes
			Min.	Max.	Min.	Max.		
Address Access Time	t_{ACC}	$\overline{CE} = \overline{OE} = V_{IL}$	—	150	—	200	ns	
$\overline{CE}$ Access Time	t_{CE}	$\overline{OE} = V_{IL}$	—	150	—	200	ns	
$\overline{OE}$ Access Time	t_{OE}	$\overline{CE} = V_{IL}$	—	60	—	70	ns	
Output Disable Time	t_{DF}	$\overline{CE} = V_{IL}$	0	50	0	55	ns	

Measurement conditions

Input pulse level0.45V and 2.4V
 Input timing reference level0.8V and 2.0V
 Output load1TTL GATE + 100pF
 Output timing reference level0.8V and 2.0V

TIME CHART



PROGRAMMING OPERATION DC CHARACTERISTICS

($V_{CC} = 6.25V \pm 0.25V$, $V_{pp} = 12.75V \pm 0.25V$, $T_a = 25^\circ C \pm 5^\circ C$)

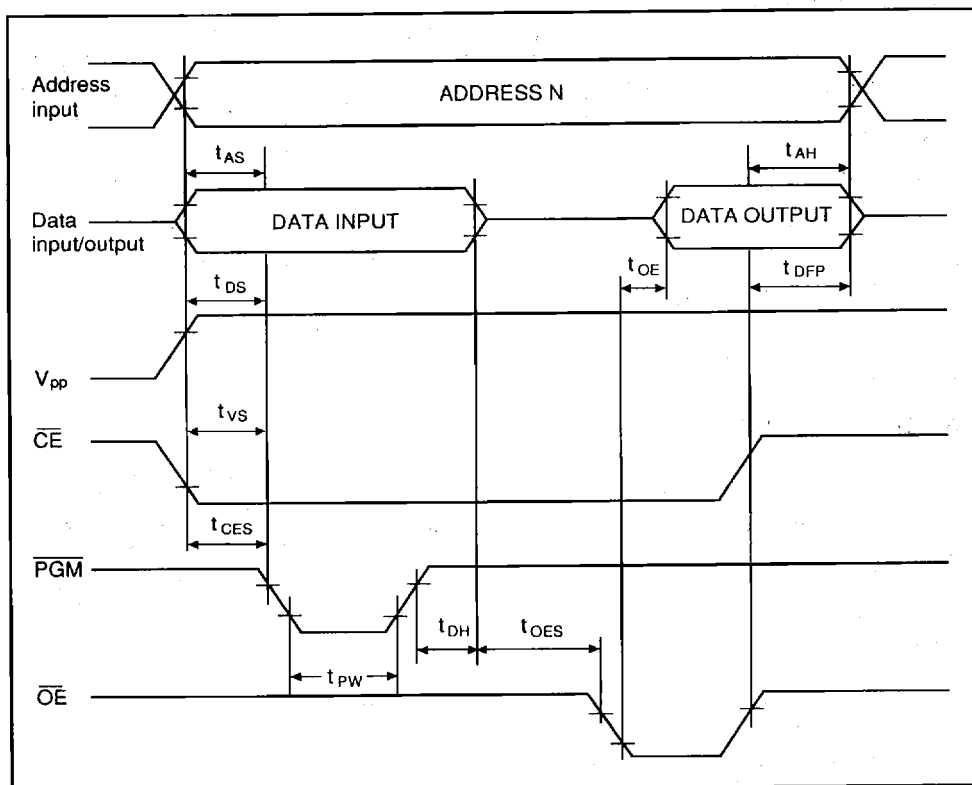
Parameter	Symbol	Conditions	MSM271024			Unit	Notes
			Min.	Typ.	Max.		
Input Leakage Current	I_{LI}	$V_{IN} = 5.25V$	—	—	10	μA	
V_{pp} Power Current	I_{pp2}	$\overline{CE} = \overline{PGM} = V_{IL}$	—	—	50	mA	
V_{CC} Power Current	I_{CC}	—	—	—	120	mA	
Input Voltage "H" Level	V_{IH}	—	2.0	—	$V_{CC} + 1$	V	
Input Voltage "L" Level	V_{IL}	—	-0.1	—	0.8	V	
Output Voltage "H" Level	V_{OH}	$I_{OH} = -400 \mu A$	2.4	—	—	V	
Output Voltage "L" Level	V_{OL}	$I_{OL} = 2.1 \text{ mA}$	—	—	0.45	V	

AC CHARACTERISTICS

($V_{CC} = 6.25V \pm 0.25V$, $V_{pp} = 12.75V \pm 0.25V$, $T_a = 25^\circ C \pm 5^\circ C$)

Parameter	Symbol	Conditions	MSM271024			Unit	Notes
			Min.	Typ.	Max.		
Address Set-up Time	t_{AS}	—	2	—	—	μS	
$\overline{OE}$ Set-up Time	t_{OES}	—	2	—	—	μS	
Data Set-up time	t_{DS}	—	2	—	—	μS	
Address Hold Time	t_{AH}	—	0	—	—	μS	
Data Hold Time	t_{DH}	—	2	—	—	μS	
Output Enable to Output Float Delay	t_{DFP}	—	0	—	130	ns	
V_{pp} Power Set-up Time	t_{VS}	—	2	—	—	μS	
$\overline{PGM}$ Program Pulse Width	t_{PW}	—	95	100	105	μS	
$\overline{CE}$ Set-up Time	t_{CES}	—	2	—	—	μS	
Data Valid from $\overline{OE}$	t_{OE}	—	—	—	150	ns	

TIME CHART



CAPACITANCE

(Ta = 25°C, f = 1 MHz, V_{CC} = 5V)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input Capacitance	C _{IN}	V _{IN} = 0V	—	—	12	pF
Output Capacitance	C _{OUT}	V _{OUT} = 0V	—	—	15	pF

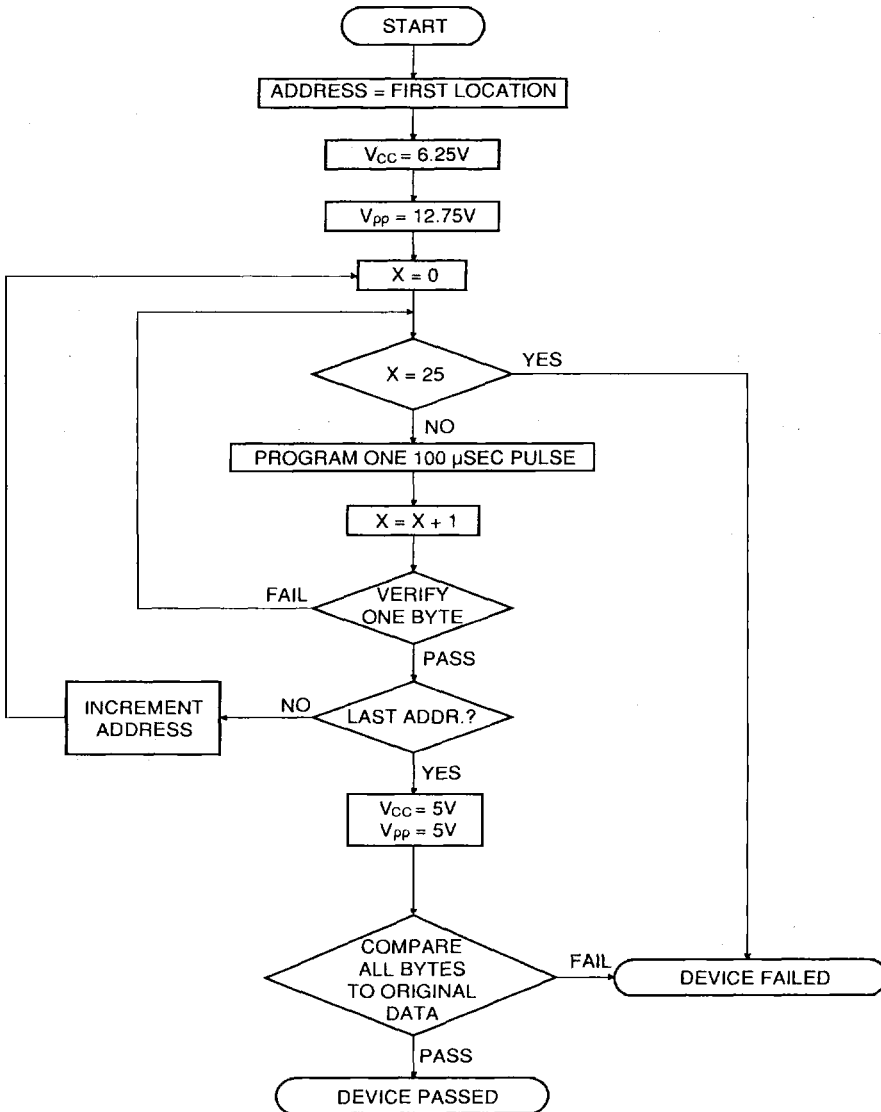
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IDENTIFIER BYTES

Code	Pins	A ₀ (21)	D ₁₅ ~D ₈ (3) ~ (10)	D ₇ (12)	D ₆ (13)	D ₅ (14)	D ₄ (15)	D ₃ (16)	D ₂ (17)	D ₁ (18)	D ₀ (19)	Hex Data
Manufacturer Code	V _{IL}		0 ~ 0	1	0	1	0	1	1	1	0	00AE
Device Code	V _{IH}		0 ~ 0	1	0	0	0	0	1	1	1	0086

Note: A₉ = 12.0 ± 0.5V

A₁ ~ A₈, A₁₀ ~ A₁₅, $\overline{\text{CE}}$, $\overline{\text{OE}}$ = V_{IL}, PGM = V_{IH} or V_{IL}, V_{pp} = V_{IH} or V_{IL}



Programming Flowchart Example